

INFLUENCE OF SYNTHESIS TEMPERATURE ON THE PHOTOELECTROCHEMICAL PROPERTIES OF Cu_2O

Urte Rinkeviciute¹, Irena Savickaja¹, Monika Skruodiene^{1,2}, Arnas Naujokaitis¹, Vidas Pakstas¹, Anatolij Sarakovskis², Milda Petruleviciene^{1,2}

¹Centre for Physical Sciences and Technology, Chemical engineering and technology, Lithuania

²University of Latvia, Institute of Solid-State Physics, Latvia

urte.rinkeviciute@ftmc.lt

Photoelectrochemical materials play an important role in converting solar energy into usable forms such as electricity or hydrogen fuel. Index Cu_2O is a promising semiconductor for these applications due to its absorption of visible light and low-cost synthesis; however, its stability and performance are often limited by photocorrosion and defect-related processes [1], [2]. Its photoelectrochemical properties are also highly sensitive to synthesis conditions, particularly the temperature used during electrode preparation [3]. The aim of this study was to evaluate the influence of synthesis temperature in the range of 30 - 80 °C on the photoelectrochemical properties of Index Cu_2O electrodes. Index Cu_2O electrodes were synthesized at different temperatures and characterized using open-circuit potential (OCP), cyclic voltammetry (CV), chronoamperometry (CA), electrochemical impedance spectroscopy (EIS).

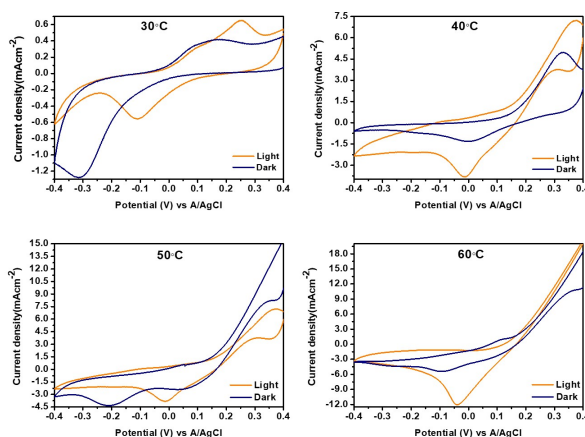


Fig. 1. CV responses of Index Cu_2O electrodes at various temperatures under light illumination (Orange) and in the dark (blue)

The CV results show a clear dependence of photoelectrochemical behavior on synthesis temperature (Fig. 1). Electrodes prepared at intermediate temperatures exhibited more stable open-circuit potentials, higher photocurrent responses, and lower charge transfer resistance, indicating improved interfacial charge transport. Investigation of temperature influence to the photoelectrochemical properties (OCP, CV, EIS and CA) will be presented and discussed in the conference.

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